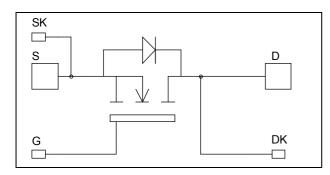


Single switch MOSFET Power Module

$$\begin{split} V_{DSS} &= 1200V \\ R_{DSon} &= 70 \text{m}\Omega \text{ typ @ Tj} = 25^{\circ}\text{C} \\ I_D &= 171 \text{A @ Tc} = 25^{\circ}\text{C} \end{split}$$



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS 7[®] FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

DK	S	
SK G		

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1200	V	
I_D	Continuous Drain Current	$T_c = 25^{\circ}C$	171		
ъ	Continuous Drain Current	$T_c = 80$ °C	126	A	
I_{DM}	Pulsed Drain current		684		
V_{GS}	Gate - Source Voltage		±30	V	
R _{DSon}	Drain - Source ON Resistance		80	mΩ	
P_D	Maximum Power Dissipation $T_c = 25^{\circ}C$		5000	W	
I_{AR}	Avalanche current (repetitive and non repetitive)		24	A	
E_{AR}	Repetitive Avalanche Energy		50	m I	
E_{AS}	Single Pulse Avalanche Energy		3200	mJ	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1200V$ $T_j = 25^{\circ}C$			1.5	mA
		$V_{GS} = 0V, V_{DS} = 1000V$ $T_j = 125^{\circ}C$			6	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 85.5A$		70	80	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 30 \text{mA}$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±600	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		43.5		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		6.6		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		1.2		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		1650		
Q_{gs}	Gate – Source Charge	$V_{Bus} = 600V$		192		пC
Q_{gd}	Gate – Drain Charge	$I_{D} = 171A$		1074		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		20		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 800V$		17		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 800 V$ $I_D = 171 A$ $R_G = 0.8 \Omega$		245		ns
T_{f}	Fall Time			62		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		7.6		T
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 800V$ $I_D = 171A, R_G = 0.8\Omega$		6.9		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		13.8		т
E _{off}	Turn-off Switching Energy	$\begin{array}{c} V_{GS} = 15V, V_{Bus} = 800V \\ I_{D} = 171A, R_{G} = 0.8\Omega \end{array}$		8.5		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_S	Continuous Source current		$Tc = 25^{\circ}C$			171	Α
	(Body diode)		$Tc = 80^{\circ}C$			126	Λ
$ m V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -171A$				1.3	V
dv/dt	Peak Diode Recovery •					18	V/ns
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C			375	ns
٠rr	reverse receivery Time	$I_S = -171A$ $V_R = 600V$	$T_j = 125$ °C			860	110
Q _{rr} Re	Reverse Recovery Charge	$di_S/dt = 600A/\mu s$	$T_j = 25$ °C		12		uС
٧rr	reverse receivery charge		$T_j = 125$ °C		54		μΟ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

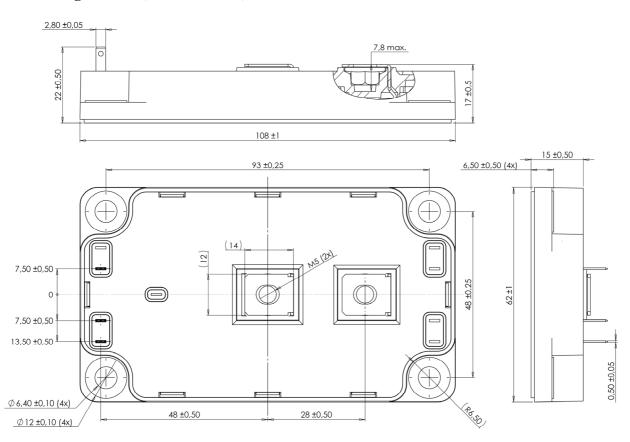
 $I_S \le$ - 171A $di/dt \le 700 A/\mu s$ $V_R \le V_{DSS}$ $T_j \le 150^{\circ} C$



Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance					0.025	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

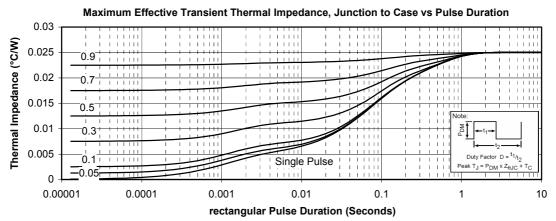
SP6 Package outline (dimensions in mm)

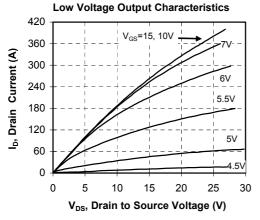


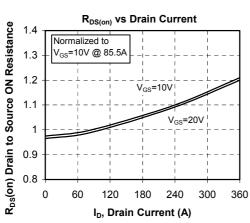
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

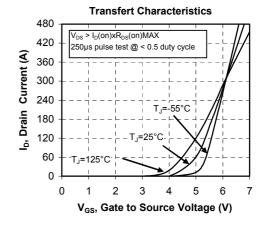


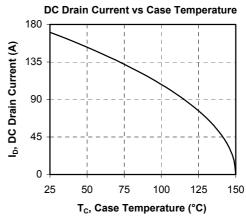
Typical Performance Curve



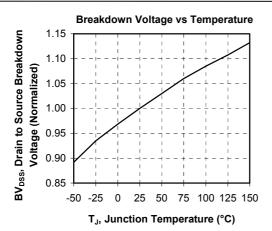


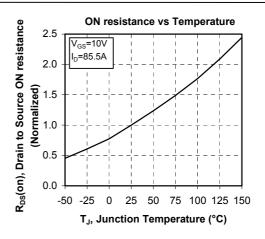


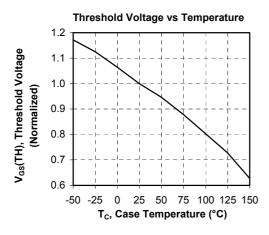


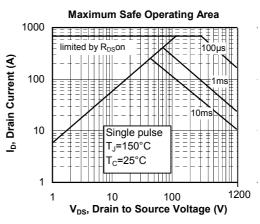


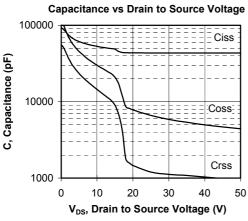


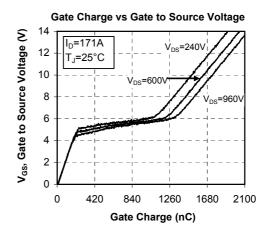




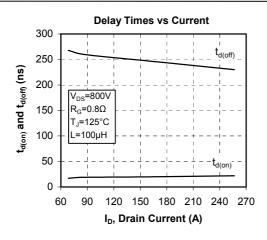


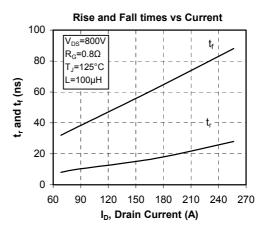


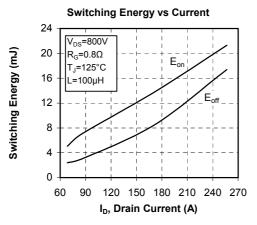


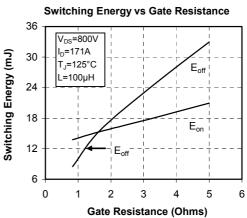


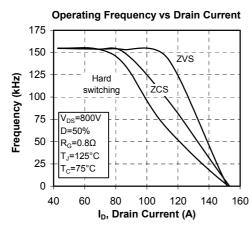


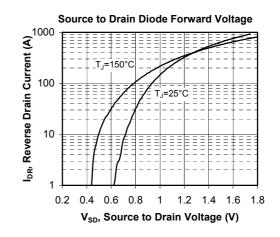












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